TRF37A73 1-6000 MHz RF Gain Block

1 Features

- 1 MHz – 6000 MHz
- Gain: 12 dB
- Noise Figure: 4.5 dB
- Output P1dB: 14.5 dBm at 2000 MHz
- Output IP3: 28.5 dBm at 2000 MHz
- Power Down Mode
- Single Supply: 3.3 V
- Stabilized Performance Over Temperature
- Unconditionally Stable
- Robust ESD: >1 kV HBM; >1 kV CDM

2 Applications

- General Purpose RF Gain Block
- Consumer
- Industrial
- Utility Meters
- Low-cost Radios
- Cellular Base Station
- Wireless Infrastructure
- RF Backhaul
- Radar
- Electronic Warfare
- Software-defined Radio
- Test and Measurement
- Point-to-Point/Multipoint Microwave
- Software Defined Radios
- RF Repeaters
- Distributed Antenna Systems
- LO and PA Driver Amplifier
- Wireless Data, Satellite, DBS, CATV
- IF Amplifier

3 Description

The TRF37A73 is packaged in a 2.00mm x 2.00mm WSON with a power down pin feature making it ideal for applications where space and low power modes are critical.

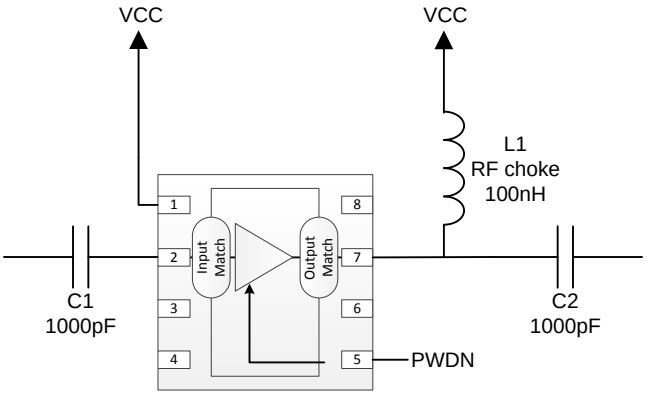
The TRF37A73 is designed for ease of use. For maximum flexibility, this family of parts uses a common 3.3 V supply and consumes 55 mA. In addition, this family was designed with an active bias circuit that provides a stable and predictable bias current over process, temperature and voltage variations. For gain and linearity budgets the device was designed to provide a flat gain response and excellent OIP3 out to 6000 MHz. For space constrained applications, this family is internally matched to 50 Ω, which simplifies ease of use and minimizes needed PCB area.

Device Information(1)

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TRF37A73	WSON (32)	2.00mm x 2.00mm

(1) For all available packages, see the orderable addendum at the end of the datasheet.

Simplified Schematic



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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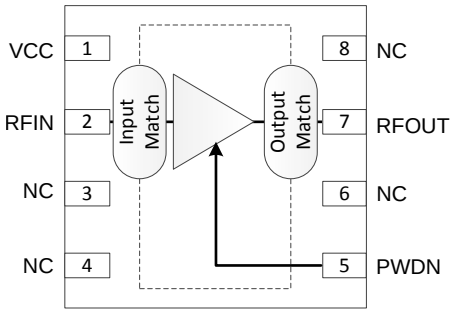
4 Revision History

DATE	REVISION	NOTES
May 2014	*	Initial release.

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5 Pin Configuration and Functions

DSG PACKAGE
(TOP VIEW)



Pin Functions

PIN		DESCRIPTION
NAME	NO.	
VCC	1	DC Bias.
RFIN	2	RF input. Connect to an RF source through a DC-blocking capacitor. Internally matched to 50 Ω.
NC	3, 4, 6, 8	No electrical connection. Connect pad to GND for board level reliability integrity.
PWDN	5	When high the device is in power down state. When LOW or NC the device is in active state. Internal pulldown resistor to GND.
RFOUT	7	RF Output and DC Bias (V_{CC}). Connect to DC supply through an RF choke inductor. Connect to output load through a DC-blocking capacitor. Internally matched to 50 Ω.
GND	PowerPAD™	RF and DC GND. Connect to PCB ground plane.

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6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)

	MIN	MAX	UNIT
Supply Input voltage	–0.3	3.6	V
Input Power		10	dBm
Operating virtual junction temperature range	–40	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 Handling Ratings

			MIN	MAX	UNIT
T_{STG}	Storage temperature range		–65	150	°C
V_{ESD}	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins (1)	–1	1	kV
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (2)	–1	1	kV

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

	MIN	NOM	MAX	UNIT
Supply Voltage, V_{CC}	3	3.3	3.45	V
Operating junction temperature, T_J	–40		125	°C

6.4 Thermal Information

THERMAL METRIC (1)		DSG	UNIT
		8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	79.3	°C/W
$R_{\theta JCtop}$	Junction-to-case (top) thermal resistance	110	
$R_{\theta JB}$	Junction-to-board thermal resistance	49	
ψ_{JT}	Junction-to-top characterization parameter	6	
ψ_{JB}	Junction-to-board characterization parameter	49.4	
$R_{\theta JCbot}$	Junction-to-case (bottom) thermal resistance	19.2	

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, SPRA953.

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6.5 Electrical Characteristics

V_{CC} = 3V3, T_A = 25°C, PWDN = Low, L_{OUT} = 100 nH, C1 = C2 = 1000 pF, Z_S = Z_L = 50 Ω (unless otherwise noted)

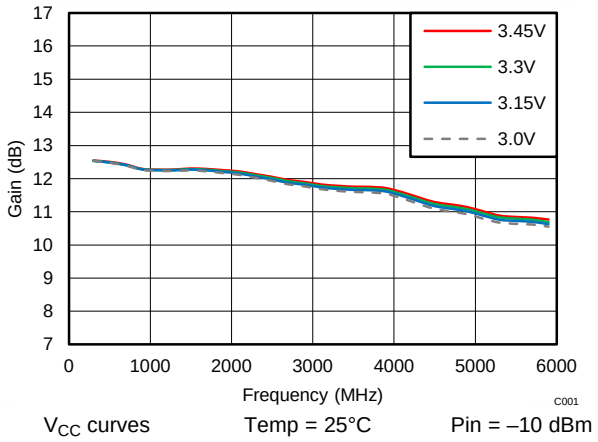
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
DC PARAMETERS						
I_{CC}	Total supply current			55	65	mA
	Power down current	PWDN = High		125		µA
P_{diss}	Power dissipation			0.182		W
RF FREQUENCY RANGE						
	Frequency range		1		6000	MHz
G	Small signal gain	f_{RF} = 400 MHz		12.5		dB
		f_{RF} = 2000 MHz		12		dB
		f_{RF} = 3000 MHz		11.5		dB
		f_{RF} = 4000 MHz		11.5		dB
		f_{RF} = 5000 MHz		11		dB
		f_{RF} = 6000 MHz		10.5		dB
OP1dB	Output 1dB compression point	At 2000 MHz		14.5		dBm
OIP3	Output 3rd order intercept point	At 2000 MHz, 2-tone 10 MHz apart		28.5		dBm
NF	Noise figure	At 2000 MHz		4.5		dB
$R_{(LI)}$	Input return loss	At 2000 MHz		16		dB
$R_{(LO)}$	Output return loss	At 2000 MHz		15		dB
PWDN PIN						
V_{IH}	High level input level		2			V
V_{IL}	Low level input level				0.8	V
I_{IH}	High level input current			30		µA
I_{IL}	Low level input current			1		µA

6.6 Timing Requirements

			MIN	TYP	MAX	UNIT
PWDN PIN						
t_{ON}	Turn-on Time	50% TTL to 90% P_{OUT}		0.6		µs
t_{OFF}	Turn-off Time	50% TTL to 10% P_{OUT}		1.4		µs

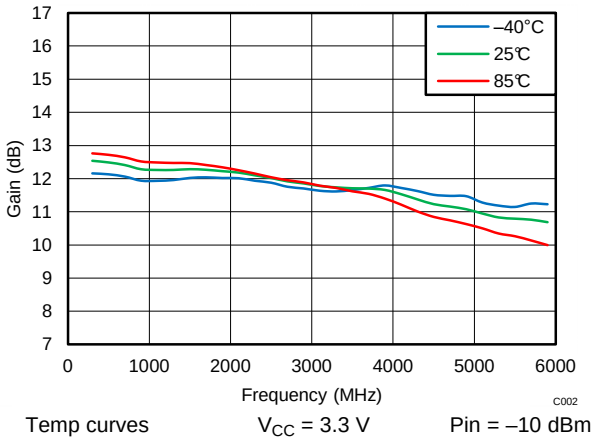
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6.7 Typical Characteristics



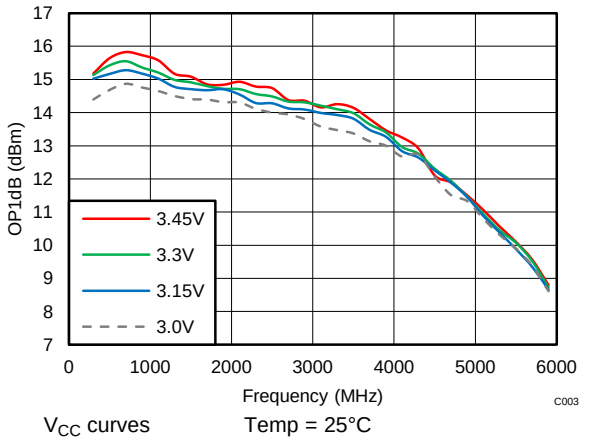
V_{CC} curves Temp = 25°C Pin = –10 dBm

Figure 1. Gain vs Frequency



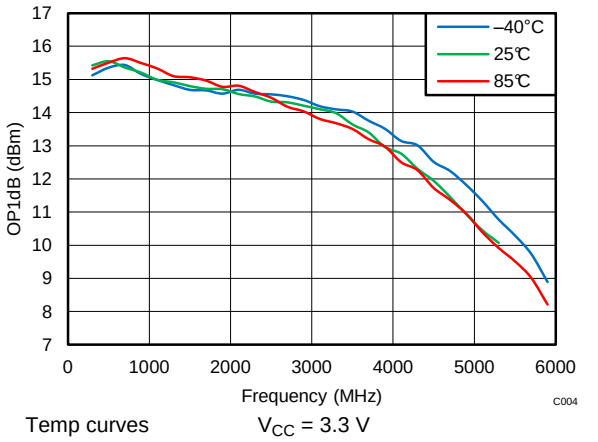
Temp curves V_{CC} = 3.3 V Pin = –10 dBm

Figure 2. Gain vs Frequency



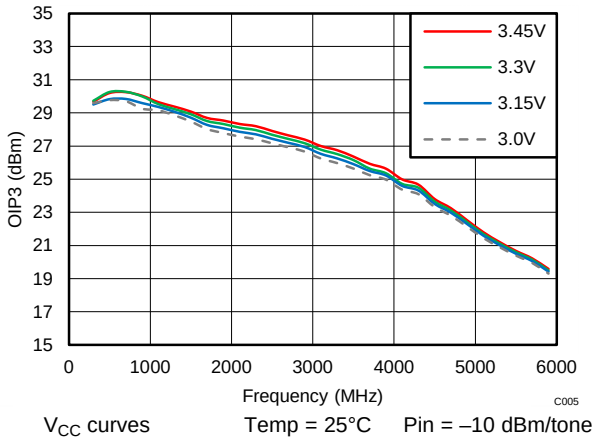
V_{CC} curves Temp = 25°C

Figure 3. OP1dB vs Frequency



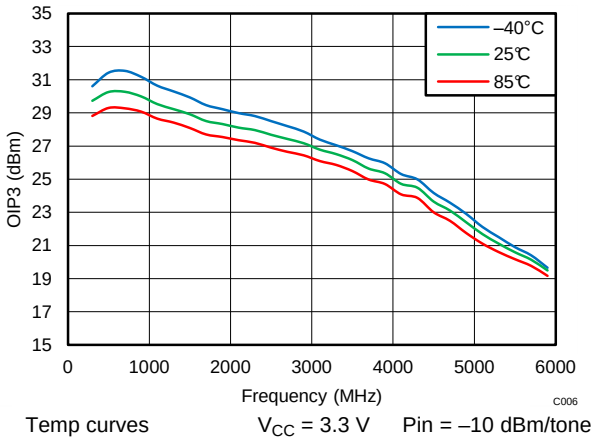
Temp curves V_{CC} = 3.3 V

Figure 4. OP1dB vs Frequency



V_{CC} curves Temp = 25°C Pin = –10 dBm/tone

Figure 5. OIP3 vs Frequency

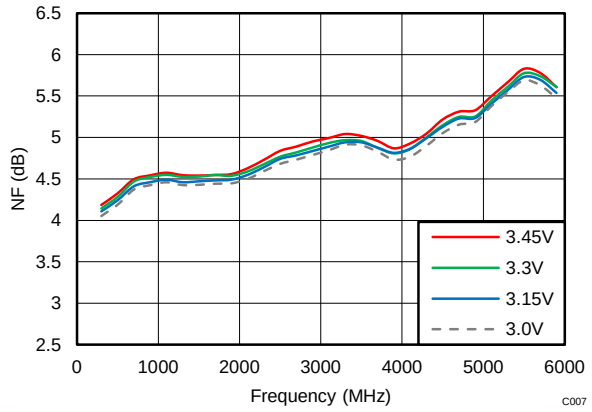


Temp curves V_{CC} = 3.3 V Pin = –10 dBm/tone

Figure 6. OIP3 vs Frequency

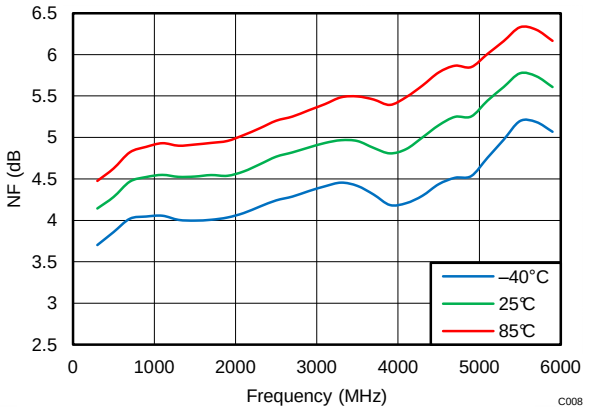
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Typical Characteristics (continued)



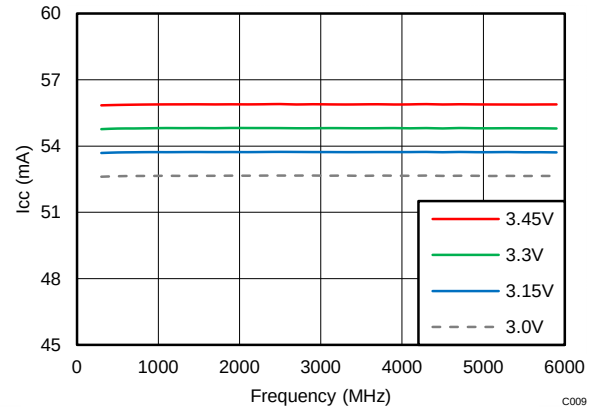
V_{CC} curves Temp = 25°C

Figure 7. NF vs Frequency



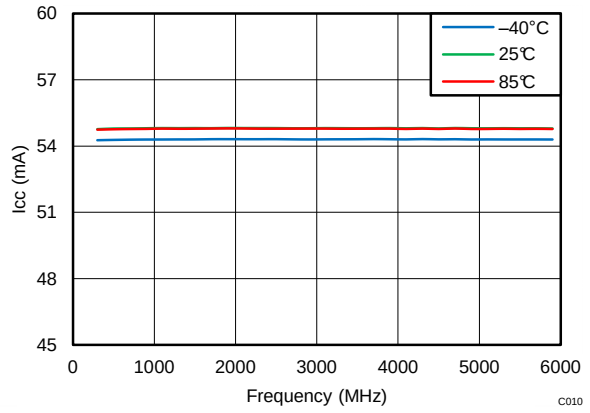
Temp curves V_{CC} = 3.3 V

Figure 8. NF vs Frequency



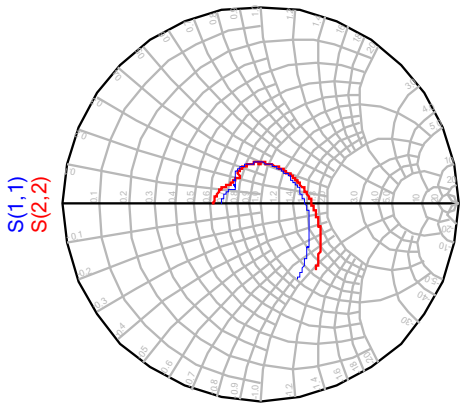
V_{CC} curves Temp = 25°C

Figure 9. I_{CC} vs Frequency



Temp curves V_{CC} = 3.3 V

Figure 10. I_{CC} vs Frequency

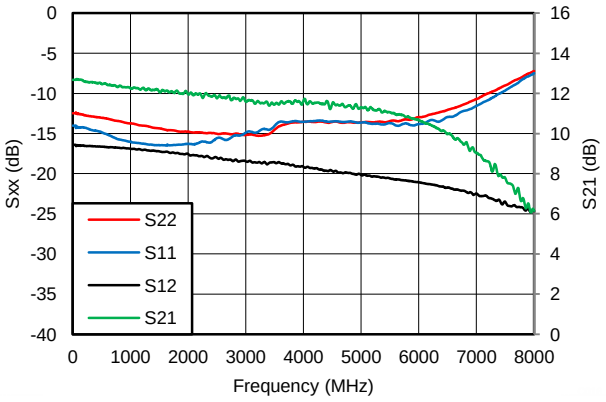


freq (1.000MHz to 8.000GHz)

V_{CC} = 3.3 V Temp = 25°C 1 MHz to 8 GHz

Data Taken with EVM and Bias T, De-embedded to DUT pin

Figure 11. Smith Chart – S11, S22



V_{CC} = 3.3 V Temp = 25°C 1 MHz to 8 GHz

Data Taken with EVM and Bias T, De-embedded to DUT pin

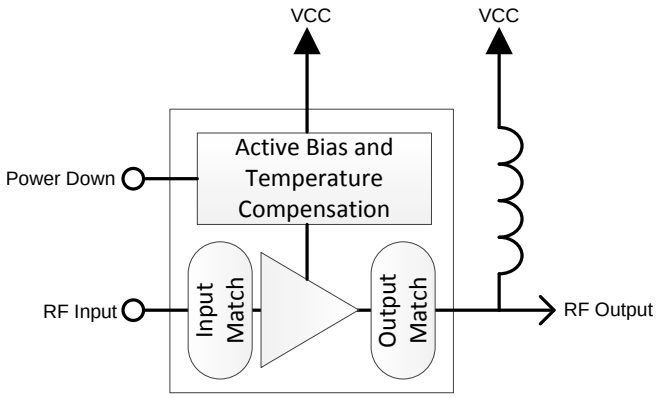
Figure 12. S22, S11, S12, S21

7 Detailed Description

7.1 Overview

The device is a 3.3 V general purpose RF gain block. It is a SiGe Darlington amplifier with integrated 50 Ω input and output matching. The device contains an active bias circuit to maintain performance over a wide temperature and voltage range. The included power down function allows the amplifier to shut down saving power when the amplifier is not needed. Fast shut down and start up enable the amplifier to be used in a host of time division duplex applications.

7.2 Functional Block Diagram



7.3 Feature Description

The TRF37A73 is a fixed gain RF amplifier. It is internally matched to 50 Ω on both the input and output. It is a fully cascadable general purpose amplifier. The included active bias circuitry ensures the amplifier performance is optimized over the full operating temperature and voltage ranges.

7.4 Device Functional Modes

7.4.1 Power Down

The TRF37A73 PWDN pin can be left unconnected for normal operation or a logic-high for disable mode operation. For applications that use the power down mode, normal 5 V TLL levels are supported.

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8 Applications and Implementation

8.1 Application Information

The TRF37A73 is a wideband, high performance, general purpose RF amplifier. To maximize its performance, good RF layout and grounding techniques should be employed.

8.2 Typical Application

The TRF37A73 device is typically placed in a system as illustrated in Figure 13.

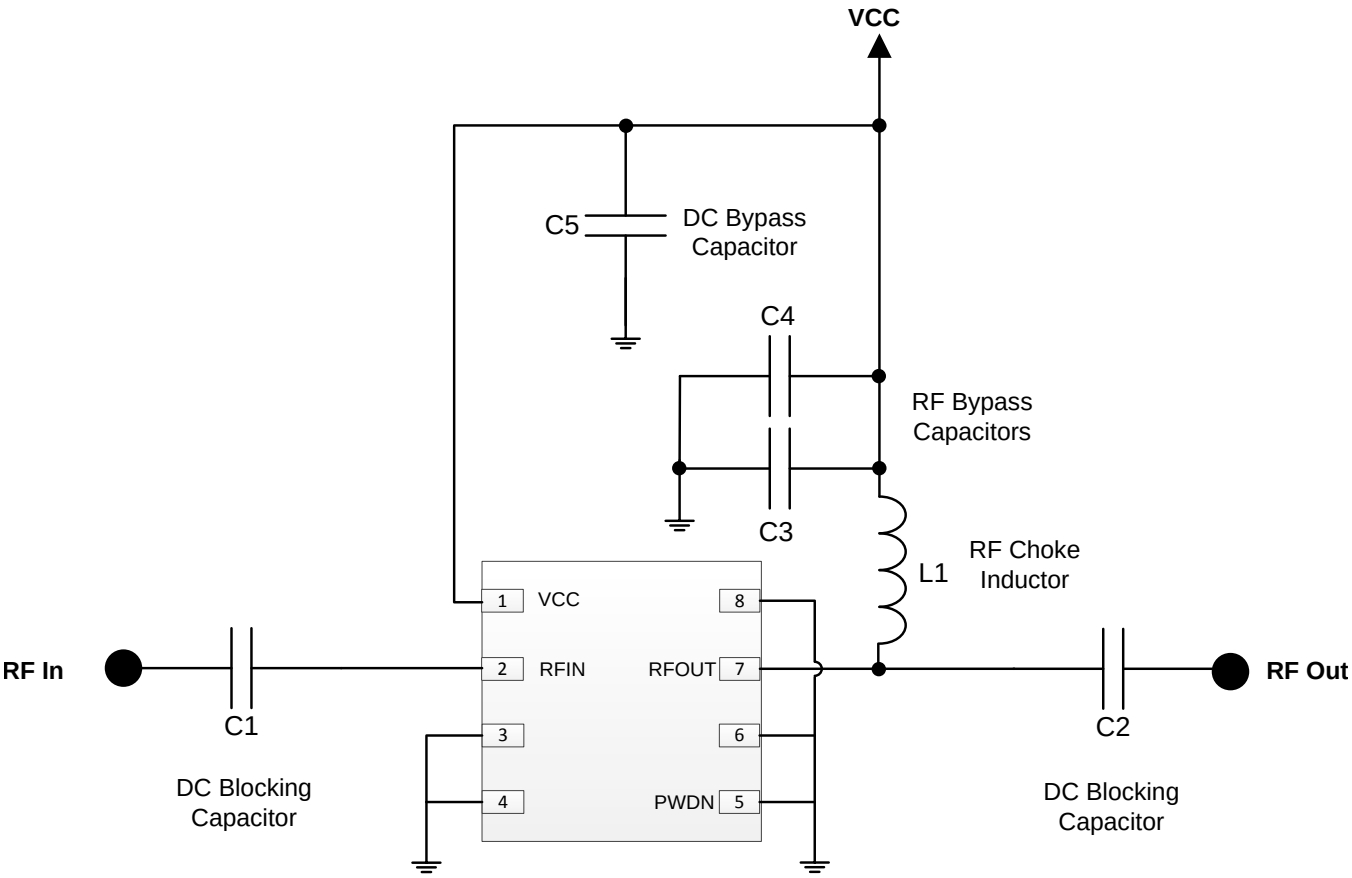


Figure 13. Typical Application Schematic for TRF37A73

8.2.1 Design Requirements

Table 1. Design Parameters

PARAMETERS	EXAMPLE VALUES
Input power range	< 3 dBm
Output power	< 18 dBm
Operating frequency range	1 — 6000 MHz

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8.2.2 Detailed Design Procedure

The TRF37A73 is a simple to use internally matched and cascadable RF amplifier. Following the recommended RF layout with good quality RF components and local DC bypass capacitors will ensure optimal performance is achieved. TI provides various support materials including S-Parameter and ADS models to allow the design to be optimized to the user's particular performance needs.

8.2.3 Application Curve

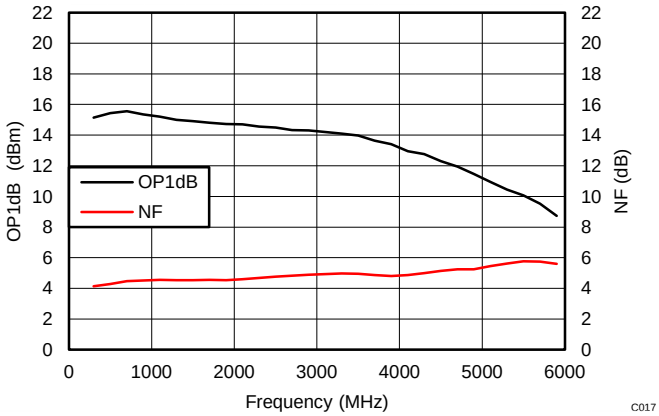


Figure 14. OP1dB and NF vs Frequency

9 Power Supply Recommendations

All supplies may be generated from a common nominal 3.3 V source but should be isolated through decoupling capacitors placed close to the device. The typical application schematic in Figure 13 is an excellent example. Select capacitors with self-resonant frequency near the application frequency. When multiple capacitors are used in parallel to create a broadband decoupling network, place the capacitor with the higher self-resonant frequency closer to the device. Expensive tantalum capacitors are not needed for optimal performance.

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10 Layout

10.1 Layout Guidelines

Good layout practice helps to enable excellent linearity and isolation performance. An example of good layout is shown in Figure 15. In the example, only the top signal layer and its adjacent ground reference plane are shown.

- Excellent electrical connection from the PowerPAD™ to the board ground is essential. Use the recommended footprint, solder the pad to the board, and do not include solder mask under the pad.
- Connect pad ground to device terminal ground on the top board layer.
- Verify that the return DC and RF current path have a low impedance ground plane directly under the package and RF signal traces into and out of the amplifier.
- Ensure that ground planes on the top and any internal layers are well stitched with vias.
- Do not route RF signal lines over breaks in the reference ground plane.
- Avoid routing clocks and digital control lines near RF signal lines.
- Do not route RF or DC signal lines over noisy power planes. Ground is the best reference, although clean power planes can serve where necessary.
- Place supply decoupling close to the device.

10.2 Layout Example

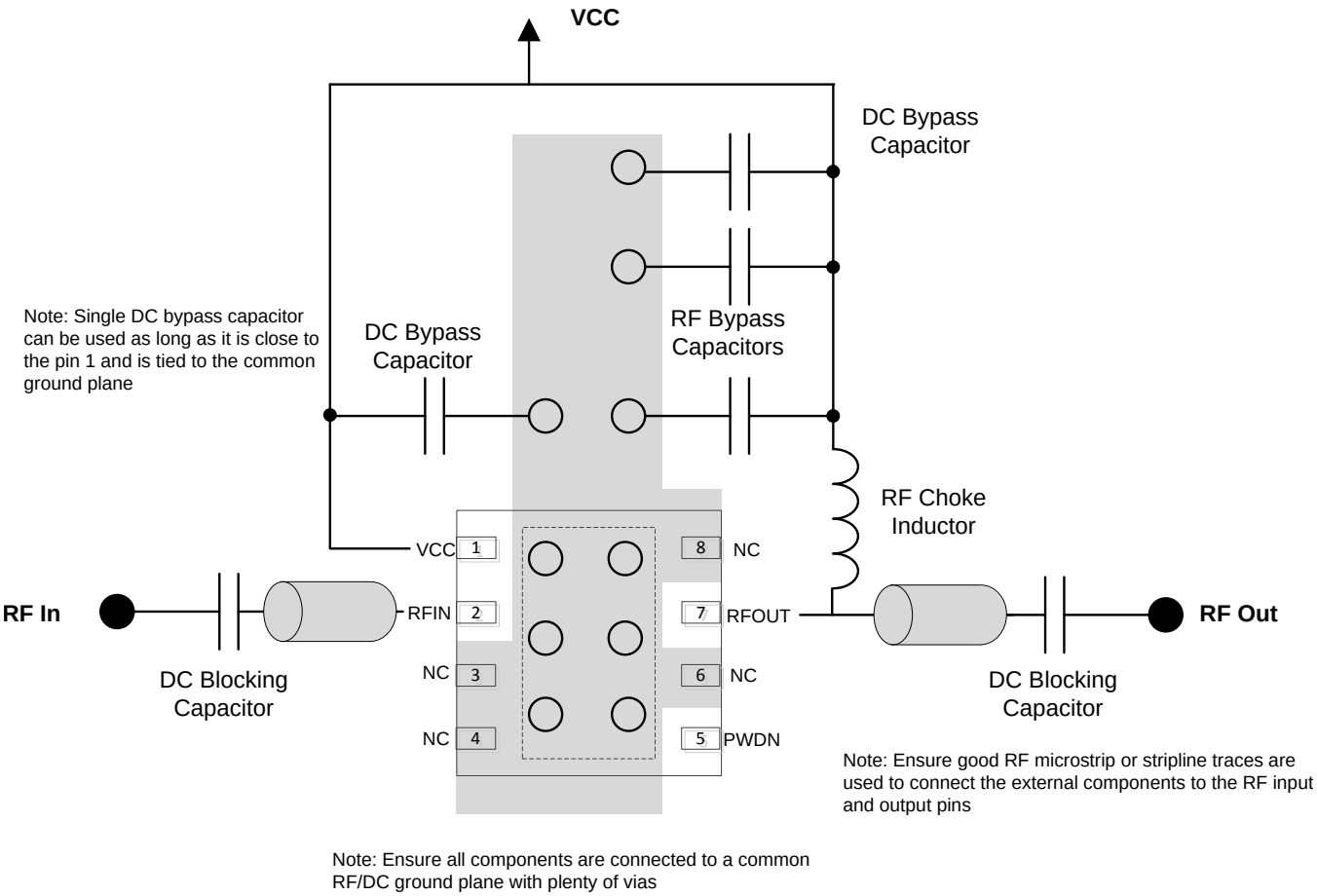


Figure 15. Layout

11 Device and Documentation Support

11.1 Trademarks

PowerPAD is a trademark of Texas Instruments.

11.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.3 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TRF37A73IDSGR	ACTIVE	WSON	DSG	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	A73I	Samples
TRF37A73IDSGT	ACTIVE	WSON	DSG	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	A73I	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

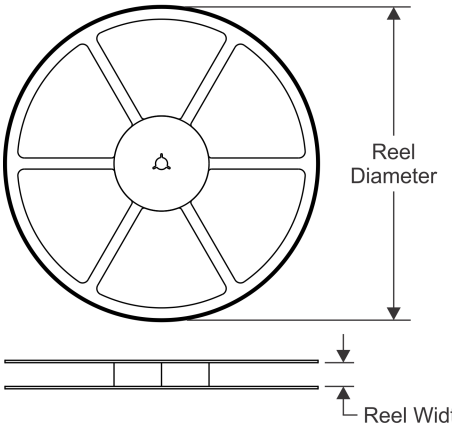
(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

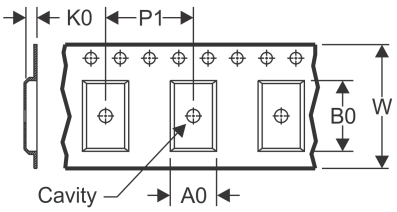
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

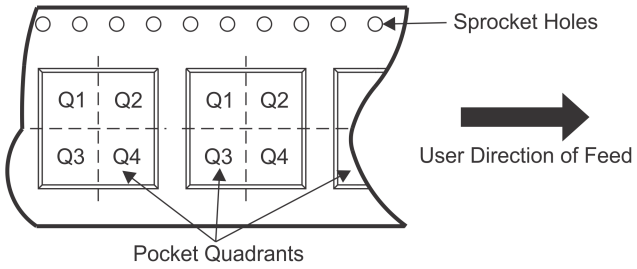


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

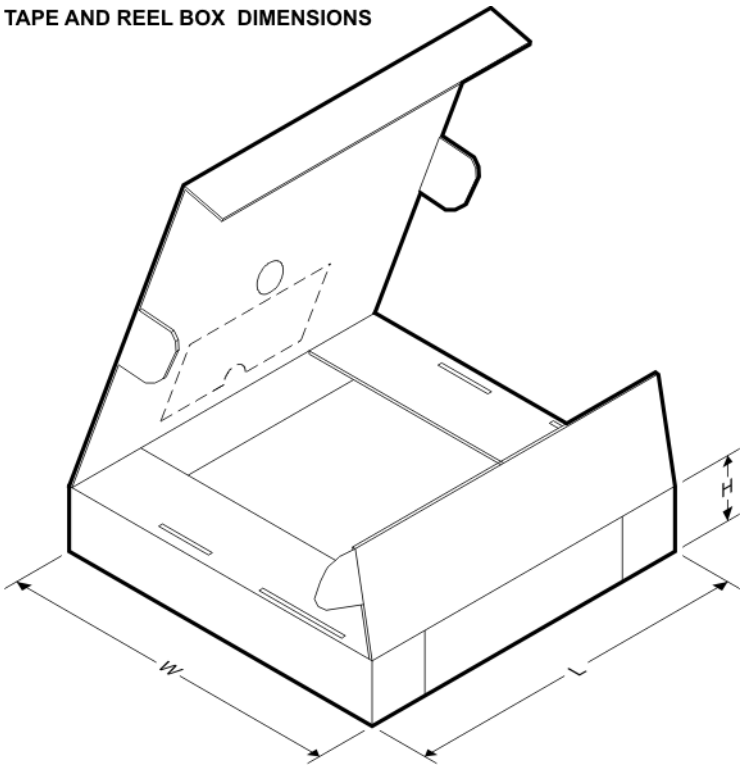
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TRF37A73IDSGR	WSON	DSG	8	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TRF37A73IDSGT	WSON	DSG	8	250	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2

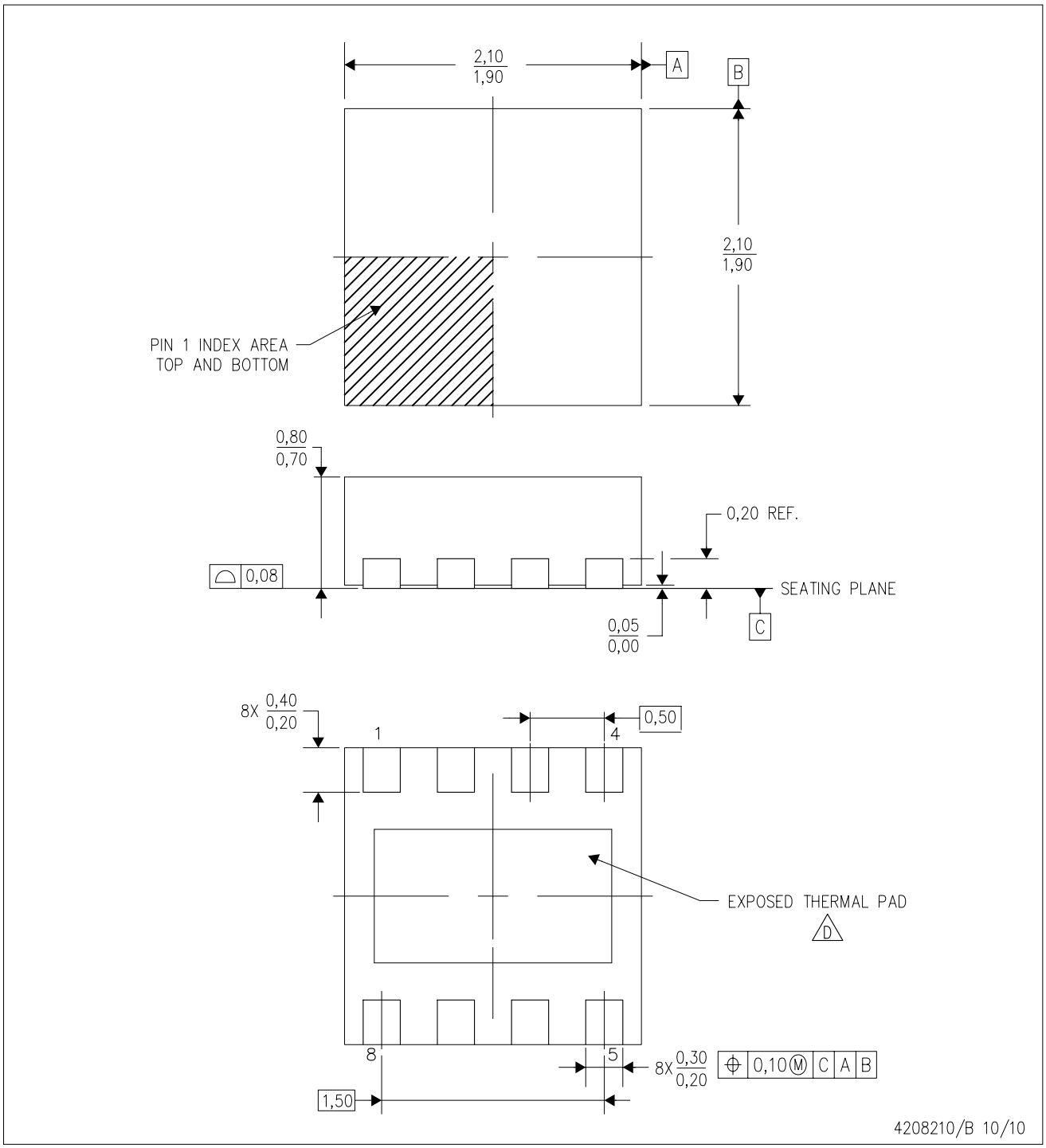
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TRF37A73IDSGR	WSON	DSG	8	3000	210.0	185.0	35.0
TRF37A73IDSGT	WSON	DSG	8	250	210.0	185.0	35.0

DSG (S–PWSON–N8) PLASTIC SMALL OUTLINE NO–LEAD



NOTES:
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.
B. This drawing is subject to change without notice.
C. Quad Flatpack, No–Leads (QFN) package configuration.
D. The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.
E. Falls within JEDEC MO–229.

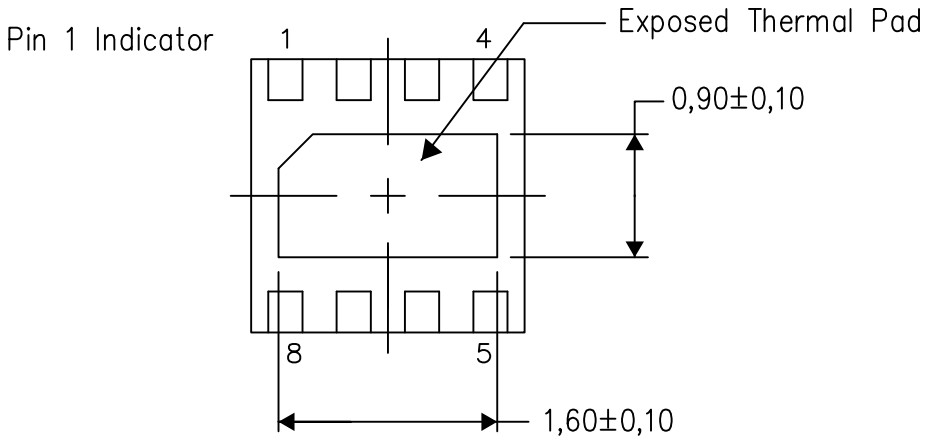
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THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No–Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



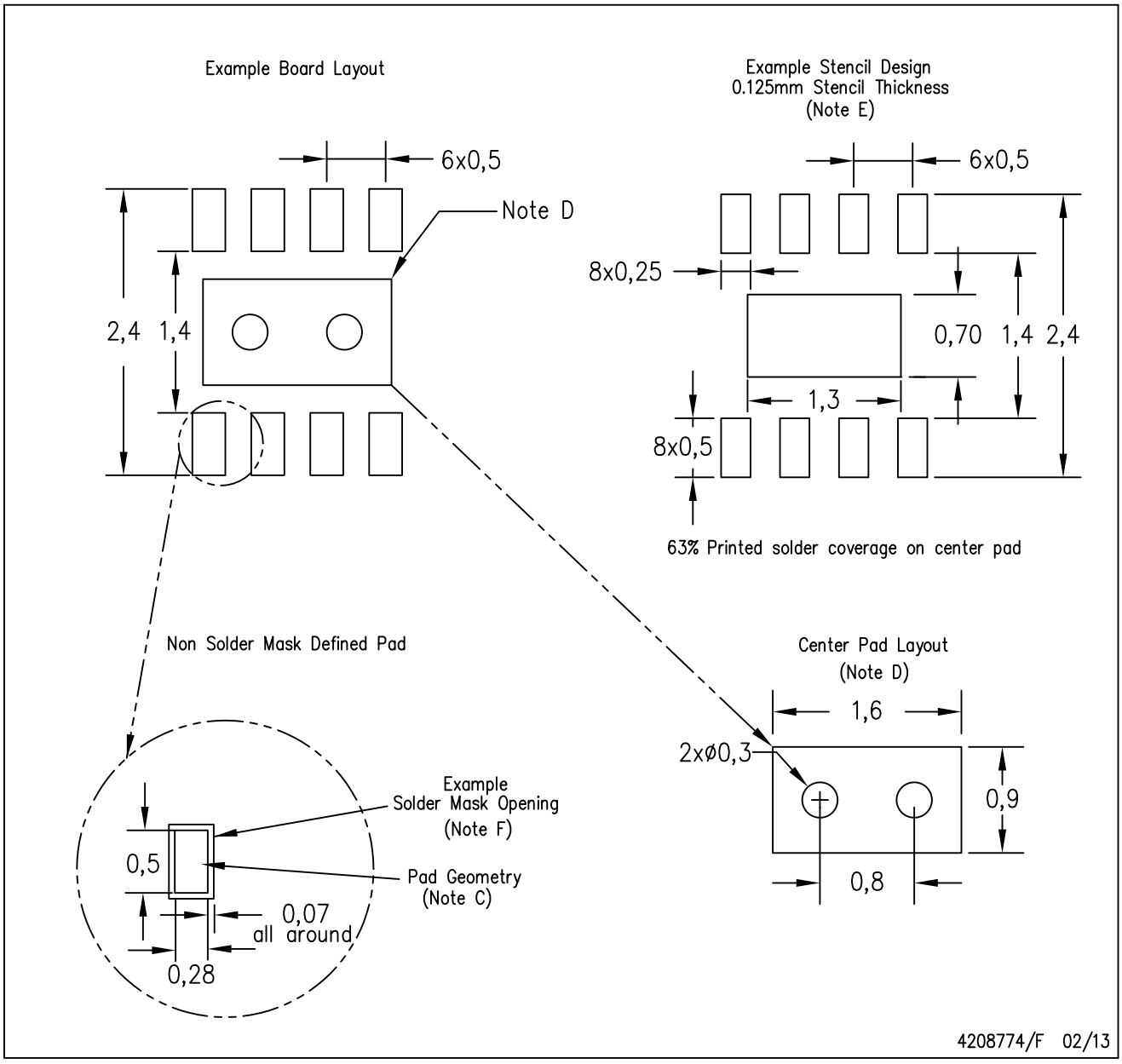
Bottom View

Exposed Thermal Pad Dimensions

4208347/G 08/13

NOTE: All linear dimensions are in millimeters

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NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http://www.ti.com>.
E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
F. Customers should contact their board fabrication site for solder mask tolerances.

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